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Vishay Semiconductors

Power Silicon Rectifier Diodes, 35 A, 40 A, 60 A



DO-203AB (DO-5)

35 A, 40 A, 60 A

DO-203AB (DO-5)

Single diode

DESCRIPTION/FEATURES

- · Low leakage current series
- Good surge current capability up to 1000 A
- Can be supplied to meet stringent military, aerospace, and other high reliability requirements



COMPLIANT

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

MAJOR RATINGS AND CHARACTERISTICS PARAMETER **TEST CONDITIONS** 1N3765 1N1183A 1N2128A UNITS 1N1183 40 (1) 35 (1) 35 (1) 60 (1) А I_{F(AV)} 140 (1) 140 (1) 150 (1) 140 (1) °C T_C 480 380 765 860 50 Hz IFSM А 60 Hz 500 (1) 400 (1) 800 (1) 900 (1) 50 Hz 1140 730 2900 3700 $I^{2}t$ A²s 670 60 Hz 1040 2650 3400 l²√t 16 100 10 300 41 000 52 500 A²√s 50 to 600 (1) 700 to 1000 ⁽¹⁾ 50 to 600 (1) 50 to 600 ⁽¹⁾ v V_{RRM} Range TJ -65 to 200 -65 to 200 -65 to 200 -65 to 200 °C

Note

(1) JEDEC[®] registered values

PRODUCT SUMMARY

I_{F(AV)}

Package Circuit configuration

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER			V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = - 65 °C TO 200 °C ⁽²⁾) V	V _{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = - 65 °C TO 200 °C ⁽²⁾) V		
VS-1N1183	VS-1N1183A	VS-1N2128A	50 ⁽¹⁾	50 ⁽¹⁾		
VS-1N1184	VS-1N1184A	VS-1N2129A	100 (1)	100 (1)		
VS-1N1185	VS-1N1185A	VS-1N2130A	150 ⁽¹⁾	150 ⁽¹⁾		
VS-1N1186	VS-1N1186A	VS-1N2131A	200 (1)	200 (1)		
VS-1N1187	VS-1N1187A	VS-1N2133A	300 (1)	300 (1)		
VS-1N1188	VS-1N1188A	VS-1N2135A	400 (1)	400 (1)		
VS-1N1189	VS-1N1189A	VS-1N2137A	500 ⁽¹⁾	500 ⁽¹⁾		
VS-1N1190	VS-1N1190A	VS-1N2138A	600 ⁽¹⁾	600 (1)		
VS-1N3765			700 (1)	700 (1)		
VS-1N3766			800 (1)	800 (1)		
VS-1N3767			900 (1)	900 (1)		
VS-1N3768			1000 (1)	1000 (1)		

Notes

Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA

(1) JEDEC® registered values

⁽²⁾ For 1N1183 Series and 1N3765 Series $T_C = -65$ °C to 190 °C

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PARAMETER	SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward curre	nt ,	1-phase operation, 180° sinusoidal conduction		35 ⁽¹⁾	35 ⁽¹⁾	40 (1)	60 ⁽¹⁾	Α
at case temperature	IF(AV)			140 ⁽¹⁾	140 ⁽¹⁾	150 ⁽¹⁾	140 ⁽¹⁾	°C
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	480	380	765	860	A
Maximum peak one cycle	law.	Half cycle 60 Hz sine wave or 5 ms rectangular pulse		500 ⁽¹⁾	400 (1)	800 (1)	900 (1)	
non-repetitive surge current	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with $\frac{1}{2} V_{\text{RRM}}$ applied following surge = 0	570	455	910	1000	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		595	475	950	1050	
Manimum 124 fau funin m		t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = T_J$ maximum	1140	730	2900	3700	A ² s
Maximum I ² t for fusing	.2.	t = 8.3 ms		1040	670	2650	3400	
Maximum I ² t for individual	— I ² t	t = 10 ms	With $V_{RRM} = 0$ following surge, initial $T_J = T_J$ maximum	1610	1030	4150	5250	
device fusing		t = 8.3 ms		1470	940	3750	4750	
Maximum l²√t for individual device fusing	²√t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage	N	T _J = 25 °C		1.7 ⁽¹⁾	1.8 ⁽¹⁾	1.3 ⁽¹⁾	1.3 ⁽¹⁾	V
at maximum forward current (IFN) V _{FM}			110	110	126	188	Α
V _{RRM} = 70	ט			-	5.0 ⁽¹⁾	-	-	
V _{RRM} = 80	D		and T	-	4.0 (1)	-	-	1
Maximum average v _{RRM} = 90) I _{R(AV)}	Maximum rated $I_{F(AV)}$ and T_{C}		-	3.0 (1)	-	-	mA
V _{RRM} = 10	00			-	2.0 (1)	-	-]
		Maximum rated IF($_{\rm AV)}$, V _{RRM} and T _C	10 ⁽¹⁾	-	2.5 ⁽¹⁾	10 ⁽¹⁾	

Notes

 $^{(1)}\ JEDEC^{\circledast}\ registered\ values$

⁽²⁾ I²t for time $t_x = I^2 \sqrt{t} x \sqrt{t_x}$

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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum operating Case temperature range T _C			- 65 to 190 ⁽¹⁾		- 65 to 200		ംറ
Maximum storage temperature range	T _{Stg}		- 65 to 175 ⁽¹⁾		- 65 to 200		C
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	1.00 ⁽¹⁾ 1.1		1.1 ⁽¹⁾	0.65 ⁽¹⁾	°C/W
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25			C/ W	
		Not lubricated thread, tighting on nut ⁽²⁾	3.4 (30)				
Maximum allowable		Lubricated thread, tighting on nut ⁽²⁾	2.3 (20)				N ⋅ m
mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon ⁽³⁾ 4.2 (37)		2 (37)	37)		
		Lubricated thread, tighting on hexagon (3)	3.2 (28)				
Approvimate weight			17			g	
Approximate weight			0.6		oz.		
Case style		JEDEC®	DO-203AB (DO-5)			D-5)	

Notes

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(1) JEDEC registered values®

⁽²⁾ Recommended for pass-through holes

⁽³⁾ Recommended for holed threaded heatsinks

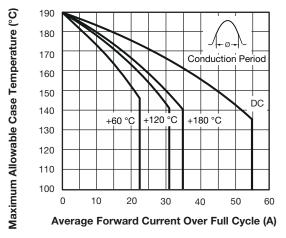


Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

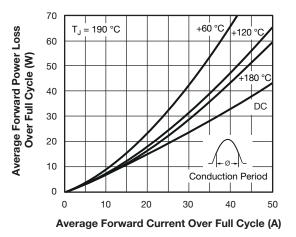
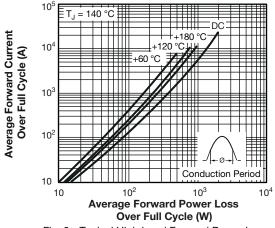


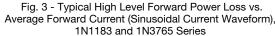
Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

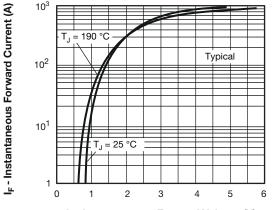
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I_F - Instantaneous Forward Voltage (V)

Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

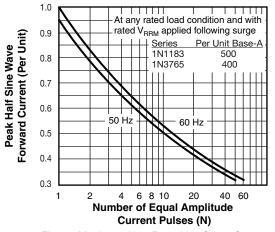
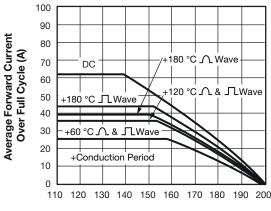
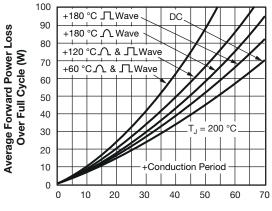


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series



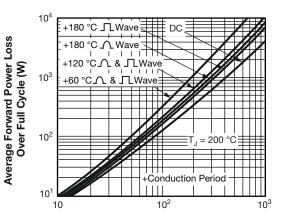
Maximum Allowable CaseTemperature (°C)

Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series



Average Forward Current Over Full Cycle (A) Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

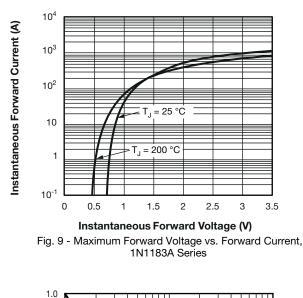
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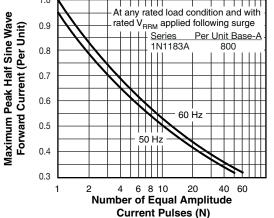
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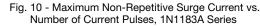


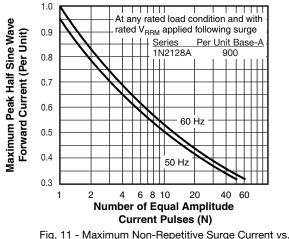


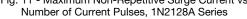
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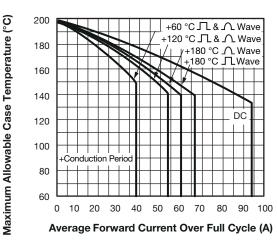
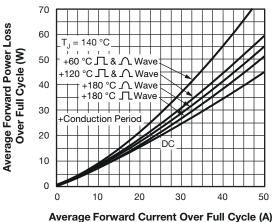
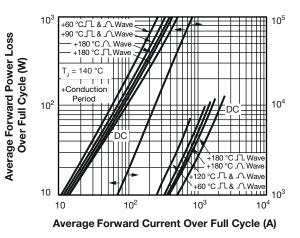


Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

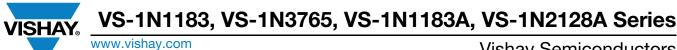




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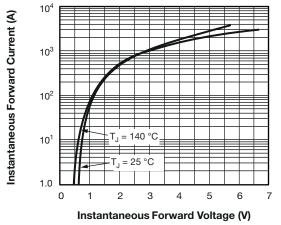


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

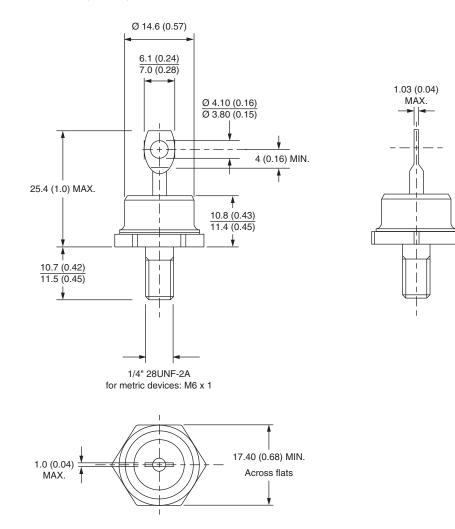
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95360		

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DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)

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